

Thyristor Module

Phase leg

Part number

MCMA200P1600SA



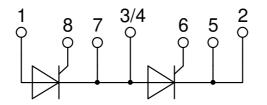
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V_{RRM}	<i>=</i> 2x 1600 V				
I _{tav}	=	200 A			
V _T	=	1.13 V			



Backside: isolated





Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- · Long-term stability
- Copper base plate with
- Direct Copper Bonded Al2O3-ceramic
- Spring contacts for solder-free dirver connection

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: SimBus A

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Gate: Spring contacts
 for solder-free PCB-mounting
- Height: 17 mm
- · Base plate: Copper
- internally DCB isolated
- Advanced power cycling

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Thyristo	r				Ratings	5	i
Symbol	Definition	Conditions		min.	typ.	max.	Uni
V _{RSM/DSM}	max. non-repetitive reverse/forwa	ard blocking voltage	$T_{VJ} = 25^{\circ}C$			1700	١
V _{RRM/DRM}	max. repetitive reverse/forward b	locking voltage	$T_{vJ} = 25^{\circ}C$			1600	١
R/D	reverse current, drain current	$V_{R/D} = 1600 V$	$T_{VJ} = 25^{\circ}C$			200	μA
		V _{R/D} = 1600 V	$T_{vJ} = 125^{\circ}C$			15	mA
V _T	forward voltage drop	$I_{T} = 200 \text{ A}$	$T_{VJ} = 25^{\circ}C$			1.16	١
		$I_{T} = 400 \text{ A}$				1.40	١
		$I_{T} = 200 \text{ A}$	$T_{vJ} = 125^{\circ}C$			1.13	١
		$I_{T} = 400 \text{ A}$				1.44	١
ITAV	average forward current	$T_c = 90^{\circ}C$	$T_{vJ} = 140^{\circ}C$			200	A
I _{T(RMS)}	RMS forward current	180° sine				314	A
V _{T0}	threshold voltage		$T_{VJ} = 140 ^{\circ}\text{C}$			0.81	١
r _T	slope resistance } for power in	oss calculation only				1.6	mΩ
R _{thJC}	thermal resistance junction to cas	se				0.15	K/W
R _{thCH}	thermal resistance case to heatsi	ink			0.08		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			760	W
I _{TSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			6.00	kA
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			6.48	kA
		t = 10 ms; (50 Hz), sine	T _{vJ} = 140°C			5.10	kA
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			5.51	k/
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{vJ} = 45^{\circ}C$			180.0	kA ² s
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			174.7	kA²s
		t = 10 ms; (50 Hz), sine	T _{v.i} = 140°C			130.1	kA ² s
	t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			126.3	kA ² s	
C	junction capacitance	$V_{B} = 400 V$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		273		pF
P _{GM}	max. gate power dissipation	t _P = 30 μs	T _c = 140°C			120	Ŵ
	<i>, , ,</i>	$t_{\rm P} = 300 \mu {\rm s}$	-			60	W
P _{GAV}	average gate power dissipation					8	N
(di/dt) _{cr}	critical rate of rise of current	$T_{v,i} = 140 ^{\circ}C; f = 50 \text{Hz}$ re	epetitive, $I_{T} = 600 \text{ A}$			150	A/μs
		$t_{\rm P} = 200 \mu {\rm s}; di_{\rm G}/dt = 0.5 {\rm A}/\mu {\rm s}; -$	•				
			on-repet., $I_{\tau} = 200 \text{ A}$			500	A/με
(dv/dt) _{cr}	critical rate of rise of voltage	$V = \frac{2}{3} V_{\text{DRM}}$	$T_{y_1} = 140^{\circ}C$			1000	1
(at) at/cr	g-	$R_{GK} = \infty$; method 1 (linear volta					
V _{gT}	gate trigger voltage	$V_{\rm D} = 6 \text{ V}$	$T_{vJ} = 25^{\circ}C$			2.5	\
■ GT	gate algger relage	v _B = o v	$T_{VJ} = -40^{\circ}C$			2.6	١
	gate trigger current	$V_{D} = 6 V$	$T_{VJ} = 40^{\circ} \text{C}$ $T_{VJ} = 25^{\circ} \text{C}$			150	m/
I _{GT}	gale ingger ourrent	v _D = 0 v	$T_{VJ} = -40^{\circ}C$			200	m/
V _{gd}	gate non-trigger voltage	$V_{\rm D} = \frac{2}{3} V_{\rm DBM}$	$T_{VJ} = -40^{\circ} \text{C}$ $T_{VJ} = 140^{\circ} \text{C}$			0.2	۱۱۱/
	gate non-trigger current	$\mathbf{v}_{\mathrm{D}} = 73 \mathbf{v}_{\mathrm{DRM}}$	1 _{VJ} = 140 O			10	
		t 00	т огоо				m/
IL	latching current	$t_p = 30 \ \mu s$ $I_G = 0.5 \ A; \ di_G / dt = 0.5 \ A / \mu s$	$T_{vJ} = 25 ^{\circ}\text{C}$			300	mA
I _H	holding current	$V_{\rm D} = 6 \ V \ R_{\rm GK} = \infty$	$T_{vJ} = 25 °C$			200	mA
t _{gd}	gate controlled delay time	$V_{\rm D} = \frac{1}{2} V_{\rm DRM}$	$T_{VJ} = 25 ^{\circ}\text{C}$			2	μ
3-		$I_{\rm G} = 0.5 \text{A}; \text{di}_{\rm G}/\text{dt} = 0.5 \text{A}/\mu\text{s}$	-				
t _q	turn-off time	$V_{\rm B} = 100 \text{ V}; \ I_{\rm T} = 200\text{ A}; \text{ V} = 3200 \text{ A}; \text{ A} = 3200 \text{ A}; \text$			150		μ
-4		$di/dt = 10 \text{ A}/\mu \text{s} dv/dt = 20 \text{ V}$					٣

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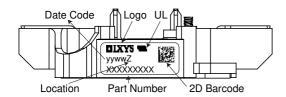
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Package SimBus A					Ratings			
Symbol	Definition	Conditions			min.	typ.	max.	Unit
	RMS current	per terminal					300	Α
T _{vj}	virtual junction temperature	•			-40		140	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		125	°C
Weight						152		g
M _D	mounting torque				3		5	Nm
M _T	terminal torque				2.5		5	Nm
d _{Spp/App}	oroonogo diatanoo on qurfa	an Latriking diatanga through air	terminal to terminal	14.0	10.0			mm
d _{Spb/Apb}	creepage distance on surra	ce striking distance through air	terminal to backside	14.0	10.0			mm
V	isolation voltage	t = 1 second			4800			V
	t = 1 minu		50/60 Hz, RMS; liso∟ ≤ 1 mA		4000			V



Part description

M = Module C = Thyristor (SCR) M = Thyristor A = (up to 1800V) 200 = Current Rating [A] P = Phase leg 1600 = Reverse Voltage [V] SA = SimBus A

SA = SimBus A

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA200P1600SA	MCMA200P1600SA	Blister	9	510387

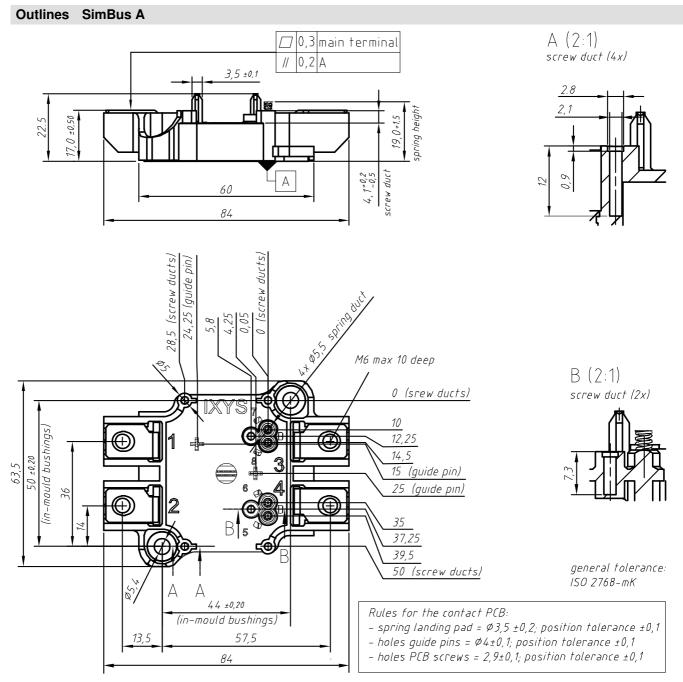
Similar Part	Package	Voltage class
MCMA200PD1600SA	Simbus A	1600

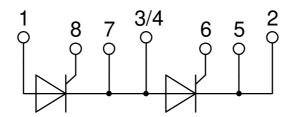
Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 140^{\circ}C$
)[R	Thyristor		
V _{0 max}	threshold voltage	0.81		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	0.8		mΩ



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